MRSS31U

Micro power Built-in IC ultra-minimum MR sensor

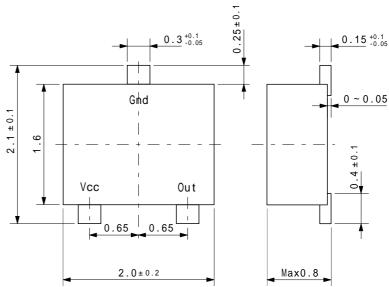
FEATURES

- *Micro power (15µW(typ):Vcc=3V) and High-sensitivity(2mT(typ)) (suited for battery-operation)
- *Ultra-small size

MR (Magneto-resistance) sensor

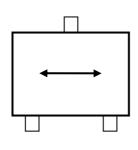
- * Volume and mounting area are 50% smaller than MRSS22L.
- * Height is about 4mm lower than MRSS22L.
- *Operating in one way magnetic field
- *Operating with independent pole (easily manufacture)
- *Superior Temperature stability
- *Lead free goods

1.Dimension (Unit:mm)

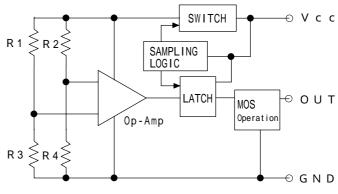


2.Fundamental Operation

2-1.Direction of Magnetic Field



2-2.Circuit Block



R1 ~ R4 : MR Elements

2-3.Performance Characteristics (25±3°C)

	Operating require Condition	Output Voltage
When power switch is ON	H = 0 mT(Magnetic Flux Density) $[0 A/m (Magnetic Field Strength)]$	Hi-level
When magnetic field is applied	$H \ge 2.0$ (Typ)mT(Magnetic Flux Density) [1.6kA/m (Magnetic Field Strength)]	Lo-level
When magnetic field is applied	$H \leq 0.5 \text{ mT}$ (Magnetic Flux Density) [0.4kA/m(Magnetic Field Strength)]	Hi-level

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3.Performance

3-1. Operating Conditions Recommended

 $(Ta = 25\pm3^{\circ}C \text{ unless otherwise specified})$

Item	Output	Condition	Min	Std	Max	Unit
Supply Voltage	-	-	2.5	3.0	3.7	V
Supply Current	-	Vcc=3V	-	5	-	μA
Ambient Temperature	-	-	-20	25	80	°C
Output Voltage	VOH	Vcc=3V Iout=2mA	2.7	-	-	V
	VOL	VCC=3V Iout=-2mA	ı	-	0.3	V
Operating Magnetic Field	Hi-level output Hon		-	2.0 (1.6)	2.5 (2.0)	mT ^{(*1}
	Lo-level output Hoff		0.5 (0.4)	-	-	(kA/m)

 $^{^{*1}}$ 1 [mT](SI) = 10 [G] (CGS)

3-2. Absolute Maximum Ratings

 $(Ta = 25\pm3^{\circ}C \text{ unless otherwise specified})$

Item	Condition	Specifications	Unit
Supply Voltage	-	5.0	V
Storage Temperature	-	-40 ~ +125	°C

The products and product specifications described in this material are subject to change without notice for reasons of modification or improvement.

 $^{^{*2)}}$ () = [kA/m](SI)

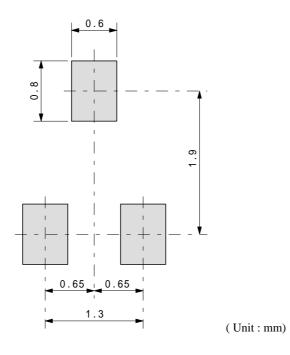


DATA SHEET

MR Sensor

MRSS31U

4. Recommended Mount Pad



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